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ONE-STEP SYNTHESIS OF DITHIOCARBAMATES FROM METAL POWDERS

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ABSTRACT

Neutral metal dithiocarbamate complexes (M(NR₂CS₂)ₓ) are well-known precursors to metal sulfides, a class of materials with numerous technological applications. We are involved in a research effort to prepare new precursors to metal sulfides using simple, reproducible synthetic procedures. We describe the results of our synthetic and characterization studies for M = Fe, Co, Ni, Cu, and In. For example, treatment of metallic indium with tetramethylthiuramdisulfide (tmtd) in 4-methylpyridine (4-Mep) at 25 °C produces a new homoleptic indium (III) dithiocarbamate, In(N(CH₃)₂CS₂)₃ (I), in yields of over 60%. The indium (III) dithiocarbamate was characterized by X-ray crystallography; (I) exists in the solid state as discrete distorted-octahedral molecules. Compound (I) crystallizes in the P1̅bar (No. 2) space group with lattice parameters: a = 9.282(1) Å, b = 10.081(1) Å, c = 12.502 Å, α = 73.91(1)°, β = 70.21(1)°, γ = 85.84(1)°, and Z = 2. X-ray diffraction and mass spectral data were used to characterize the products of the analogous reactions with Fe, Co, Ni, and Cu. We discuss both use of dithiocarbamates as precursors and our approach to their preparation.

INTRODUCTION

Technological applications for metal sulfides are numerous. Many applications take advantage of the photoelectrical or electrical properties of these materials in electronic applications such as solar cells, infrared detectors, light-emitting diodes, and transistors (e.g. CdS, GaS, and CulnS₂) [1,2]. Chevrel phases are superconducting, for example PbMo₆S₈ has a Tc of 21K [3]. An example of a chemical application is the use of heterogeneous systems such as Co-promoted molybdenum sulfide (Ni or W are sometimes substituted for Co and Mo) on γ-alumina catalysts for metal and sulfur removal under H₂ from crude oil, this allows efficient or environmentally sound use of "dirtier" feedstocks [4]. Chemical sensitization to form AgAuₓSᵧ clusters on silver halide grains is an integral step in producing photographic film [5]. It is also interesting to note that many enzymes and electron transfer proteins have metal—sulfide cluster active sites [6].

As part of an in-house and external effort to synthesize and use metal sulfides and selenides as precursors for photovoltaic and related optoelectronic applications [2,7-9], we are exploring synthetic aspects of metal calcogenede chemistry. One very well-studied class of compounds is neutral, homoleptic metal dithiocarbamates of the formula M(NR₂CS₂)ₓ [10]. There are several typical synthetic routes to these compounds including reaction of CS₂ with metal amide complexes (M(NR₂)ₓ), reaction of metal chlorides with CS₂ in the presence of amines, and direct reaction of metal halides with the sodium dithiocarbamate salt [6]. Less typically discussed are reactions involving metal powders [11,12]. We have determined that a wide range of metals will react directly with tetraalkylthiuram disulfides to form homoleptic dithiocarbamates including Fe, Co, Ni, Cu, and In, in the case of indium producing a new dithiocarbamate (N(CH₃)₂CS₂)₃ (I). We also discuss mass spectral data on several transition metal complexes and relate it to their potential uses as precursors in chemical vapor deposition (CVD) and other deposition technologies.

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EXPERIMENTAL

All manipulations of moisture and air-sensitive materials were done under an inert atmosphere by standard Schlenk techniques on a double-manifold vacuum line or in a Vacuum Atmospheres Co. glovebox equipped with a HE-493 dri-train. Solvents were freshly distilled from benzophenone ketyl prior to use. Metal powders were obtained from Strem Chemicals, Newburyport, MA. Sulfur compounds were obtained from Aldrich Chemical Co., Milwaukee, WI. Infrared spectra were recorded on a Perkin-Elmer 599B spectrophotometer. Electron impact mass spectra (25 and 70 eV, 150°C) were recorded on a Finnigan TSQ-45 mass spectrometer. Single crystal X-ray analyses were done on an Enraf-Nonius CAD-4 diffractometer.

RESULTS AND DISCUSSION

Metal dithiocarbamates were typically prepared by reaction of metal powder (M = Fe, Co, Ni, Cu, and In) (0.50 g) and stoichiometric amounts of tetraalkylthiuramdisulfides (for R = Me, tmtd; R = Et, tetd) in 35 mL of 4-methylpyridine at ambient temperature for several days, equation 1. The reaction was filtered, and the resulting solution was layered with hexanes. Hexanes, 150 mL, was added to the resulting dark brown or black material to further precipitate solid.

\[
M^0 + \frac{n}{2} R_2NC(S)S-SC(S)NR_2 \rightarrow M(NR_2CS_2)_n
\]

For example, treatment of metallic indium with tmtd in 4-Mepy at 25 °C produces In(N(CH₃)₂CS₂)₃ (I), in yields of over 60%. The indium (III) dithiocarbamate was characterized by X-ray crystallography; (I) exists in the solid state as discrete distorted-octahedral molecules, figure 1. Compound (I) is only the second indium dithiocarbamate to be structurally characterized [13]. Compound (I) crystallizes in space group P1bar (No. 2), lattice parameters: \(a = 9.282(1) \text{ Å}, b = 10.081(1) \text{ Å}, c = 12.502 \text{ Å}, \alpha = 73.91(1)^\circ, \beta = 70.21(1)^\circ, \gamma = 85.84(1)^\circ\), and \(Z = 2\). Single crystal X-ray diffraction data were collected as well for Cu(N(C₂H₅)₂CS₂)₂, which has been previously structurally characterized [14]. The complexes that were isolated were both divalent (M = Ni and Cu) and trivalent (M = Fe, Co, and In) for R = Me and Et with structures analogous to the Cu and the In, respectively.

Figure 1. - ORTEP drawings of In(N(CH₃)₂CS₂)₃ and Cu(N(C₂H₅)₂CS₂)₂ with key atoms labelled. The thermal ellipsoids enclose 50 % of electron density.
Table 1.

MASS SPECTRA OF METAL DIMETHYLDITHIOCARBAMATES

First numbers are m/z values. Numbers in brackets are relative intensities.

<table>
<thead>
<tr>
<th>ION</th>
<th>METALS M</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Cu</td>
</tr>
<tr>
<td>M+</td>
<td>63,65 (11.9,5.2)</td>
</tr>
<tr>
<td>[CH₃NCS]+</td>
<td>73 (15.8)</td>
</tr>
<tr>
<td>[(CH₃)₂NCS]+</td>
<td>88 (100)</td>
</tr>
<tr>
<td>[(CH₃)₂NCS₂]+</td>
<td>120 (10.2)</td>
</tr>
<tr>
<td>MS₂⁺</td>
<td>127,129 (2.9,1.5)</td>
</tr>
<tr>
<td>[MSCNCH₃]+</td>
<td>136,138 (14.3,7.1)</td>
</tr>
<tr>
<td>[MS₂CN(CH₃)₂]+</td>
<td>183,185 (28.8,15.9)</td>
</tr>
<tr>
<td>[M(S₂CN(CH₃)₂)₂]+</td>
<td>303,305 (74.0,56.8)</td>
</tr>
<tr>
<td>[M(S₂CN(CH₃)₂)₃]+</td>
<td>423,425 (-,-)</td>
</tr>
</tbody>
</table>
It was previously reported that room-temperature reaction of copper and nickel powders with sodium dithiocarbamates and photochemical reaction of copper powder with tetraalkylthiuramdisulfides (tatd) in CHCl₃ produce metal dithiocarbamates [11,12]. We and others have discovered that in strong basic, coordinating solvents such as 4-MePy, species such as S₈, REER (R = alkyl or aryl, E = S or Se) and (C₆H₅CO₂)₂O₂ will oxidize metal powders [15-19]. The advantage of reaction (1) is the lack of by-products. Production of dithiocarbamates via oxidation of metal powders results in a much greater control of impurities, first by the use of metal powders as a starting material and second by simplicity in the chemistry that results in only one product.

The dithiocarbamates prepared for M = Fe, Co, Ni, and Cu were examined by mass spectrometry. A diagram of the instrument used in these studies is shown in figure 2. A summary of relevant mass spectral data is given in table 1. All of the metal complexes show characteristic peaks corresponding to breakdown of the dimethylthiocarbamate residues. Each compound gives an ion at m/z 120 corresponding to the dimethylthiocarbamate residue itself. Each spectrum has as its base peak, m/z 88 with 100 %, consistent with loss of a sulfur atom, (CH₃)₂NCS⁺. Finally, each compound has a peak at m/z corresponding to the methyl isocyanate ion produced by the loss of a methyl and sulfide ion. The organic fragments for all metal complexes were of approximately the same intensity.

The parent ions of the trivalent Fe and Co occur at m/z 416 and 419, respectively. The parent ions of both trivalent complexes are less intense than for Cu and Ni, expected due to the highest molecular weights; a crude ordering of volatilities from this data is Cu > Ni > Co > Fe. The dithiocarbamate-loss fragment ML₂⁺ (Co: 299, Fe: 296) of both Fe and Co are much more intense than the corresponding parent ions and the analogous Ni and Cu species ML⁺. The rationale for the intensity of these ions is two-fold: the stability of Fe²⁺ and Co²⁺ relative to monovalent Ni and Cu and the greater volatility of a lower-mass fragment. The stability argument is born out by the relative weakness of the FeL⁺ and CoL⁺ peaks. Finally, the M⁺ peaks of Co and Fe are weak, Fe approximating Ni while Co is weakest, approximately following trends in the metals' boiling points [20]. The MS₂⁺ ions for Fe and Co are essentially non-existent.

Figure 2. - Schematic diagram of Finnigan TSQ-45 mass spectrometer used in this study.
Metal dithiocarbamates have been shown to cleanly produce metal sulfides, both as bulk [21] and thin-film material [22,23]. Work by others is focused on producing dithiocarbamates with substituted or additional ligands to enhance volatility [24-26] and/or minimize dimerization that occurs with Zn diethylldithiocarbamate, for example [27,28]. For these complexes, the chemistry that we describe would be useful as a method to prepare a variety of dithiocarbamates for further reaction to the sulfide precursors. Another example of use of dithiocarbamates is the use of copper di-n-butyldithiocarbamate to prepare a single-molecule precursor to CuInS2 [29]. Work is currently underway in our labs to exploit this chemistry to prepare precursors for binary and ternary sulfides.

CONCLUSIONS

We have described a simple one-step synthesis to metal dithiocarbamates by oxidation of metal powders with dialkylthiuram dilsulfides in a basic coordinating solvent. Dithiocarbamates are excellent precursors to metal sulfides, an important class of materials for a number of applications. The structure of In(N(CH3)2CS2)3, a distorted octahedron and only the second structurally-characterized indium dithiocarbamate, was briefly described. Mass spectral data on Fe, Co, Ni, and Cu dimethyldithiocarbamate indicate that all four are reasonably volatile. Both the divalent and trivalent compounds had fairly intense ML2+ ion peaks, the M+ and MS2+ (for Cu, Ni, and Co) though weaker, were present. The mass spectral data demonstrates the key attributes of dithiocarbamates: volatility, relative stability in the gas phase, and ample decomposition pathways for clean production of metal sulfide.

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